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September 2013

FGB40N60SM 600 V, 40 A Field Stop IGBT

Features

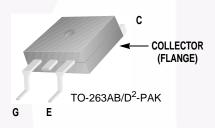
- Maximum Junction Temperature: T_J =175°C
- Positive Temperaure Co-efficient for Easy Parallel Operating
- **High Current Capability**
- Low Saturation Voltage: V_{CE(sat)} = 1.9 V(Typ.) @ I_C = 40 A
- High Input Impedance
- Fast Switching
- Tighten Parameter Distribution
- RoHS Compliant
- IR Reflow Only

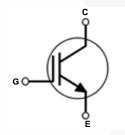
Applications

· Welder, PFC

General Description

Using novel field stop IGBT technology, Fairchild's new series of field stop 2nd generation IGBTs offer the optimum performance for welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V_{GES}	Gate to Emitter Voltage		± 20	V
V GES	Transient Gate to Emitter Voltage		± 30	V
la	Collector Current	@ T _C = 25°C	80	A
IC	Collector Current	@ T _C = 100°C	40	А
I _{CM (1)}	Pulsed Collector Current		120	A
P _D	Maximum Power Dissipation	@ T _C = 25°C	349	W
' D	Maximum Power Dissipation	@ T _C = 100°C	174	W
TJ	Operating Junction Temperature		-55 to +175	°C
T _{stg}	Storage Temperature Range		-55 to +175	°C
T _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds		300	°C

Notes:1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.43	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	-	62.5	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGB40N60SM	FGB40N60SM	TO-263AB(D ² -PAK)	-	-	50

Electrical Characteristics of the IGBT $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	teristics					
BV _{CES}	Collector to Emitter Breakdown Voltage	$V_{GE} = 0V, I_{C} = 250\mu A$	600	-	-	V
$\frac{\Delta BV_{CES}}{\Delta T_{J}}$	Temperature Coefficient of Breakdown Voltage	$V_{GE} = 0V, I_C = 250\mu A$	-	0.6	-	V/°C
I _{CES}	Collector Cut-Off Current	$V_{CE} = V_{CES}, V_{GE} = 0V$	-	-	250	μΑ
I _{GES}	G-E Leakage Current	$V_{GE} = V_{GES}, V_{CE} = 0V$	-	-	±400	nA
On Charac	teristics					
V _{GE(th)}	G-E Threshold Voltage	$I_{C} = 250 \mu A, V_{CE} = V_{GE}$	3.5	4.5	6.0	V
		$I_C = 40A, V_{GE} = 15V$	-	1.9	2.3	V
V _{CE(sat)}	Collector to Emitter Saturation Voltage	$I_C = 40A, V_{GE} = 15V,$ $T_C = 175^{\circ}C$	-	2.1	-	V
Dynamic C	haracteristics					
C _{ies}	Input Capacitance		-	1880	-	pF
C _{oes}	Output Capacitance	$V_{CE} = 30V_{,} V_{GE} = 0V_{,}$ f = 1MHz	-	180	-	pF
C _{res}	Reverse Transfer Capacitance	T = TIVIMZ	-	50	-	pF
Switching	Characteristics		•			
t _{d(on)}	Turn-On Delay Time		- /	12	16	ns
t _r	Rise Time		-	20	28	ns
t _{d(off)}	Turn-Off Delay Time	$V_{CC} = 400V, I_{C} = 40A,$ $R_{G} = 6\Omega, V_{GE} = 15V,$	-	92	120	ns
t _f	Fall Time		-	13	17	ns
E _{on}	Turn-On Switching Loss	Inductive Load, T _C = 25°C	-	0.87	1.30	mJ
E _{off}	Turn-Off Switching Loss		-	0.26	0.34	mJ
E _{ts}	Total Switching Loss		-	1.13	1.64	mJ
t _{d(on)}	Turn-On Delay Time		-	15	-	ns
t _r	Rise Time		-	22	-	ns
t _{d(off)}	Turn-Off Delay Time	V_{CC} = 400V, I_{C} = 40A, R_{G} = 6 Ω , V_{GE} = 15V, Inductive Load, T_{C} = 175°C	-	116	-	ns
t _f	Fall Time		-	16	-	ns
E _{on}	Turn-On Switching Loss		-	0.97	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.60	-	mJ
E _{ts}	Total Switching Loss		-	1.57	-	mJ

Electrical Characteristics of the IGBT (Continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max	Unit
Q_g	Total Gate Charge		-	119	180	nC
Q _{ge}	Gate to Emitter Charge	$V_{CE} = 400V, I_{C} = 40A,$ $V_{GE} = 15V$	-	13	20	nC
Q _{ac}	Gate to Collector Charge	VGE = 13V	-	58	90	nC

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

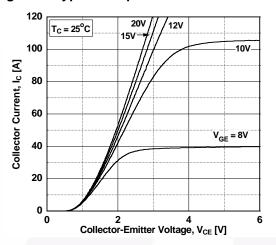


Figure 3. Typical Saturation Voltage Characteristics

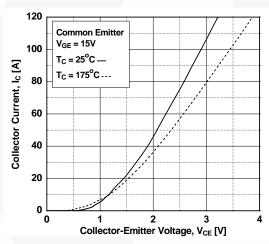


Figure 5. Saturation Voltage vs. V_{GE}

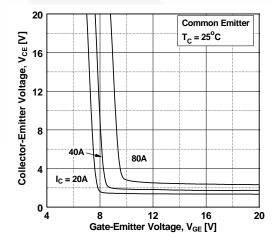


Figure 2. Typical Output Characteristics

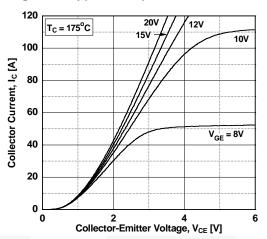


Figure 4. Saturation Voltage vs. Case
Temperature at Variant Current Level

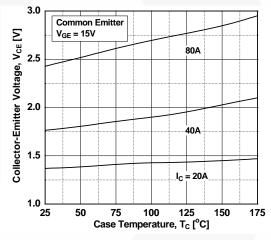
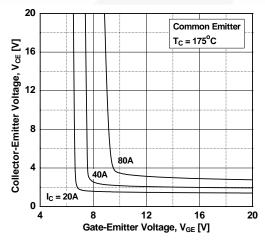


Figure 6. Saturation Voltage vs. V_{GE}



Typical Performance Characteristics

Figure 7. Capacitance Characteristics

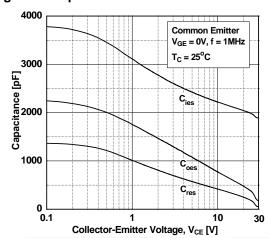


Figure 8. Gate charge Characteristics

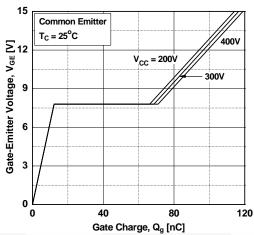


Figure 9. Turn-on Characteristics vs.
Gate Resistance

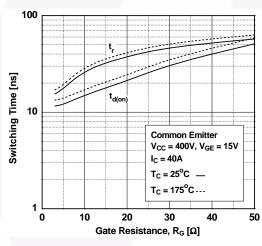


Figure 10. Turn-off Characteristics vs.
Gate Resistance

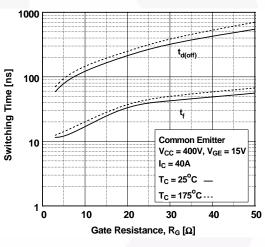


Figure 11. Switching Loss vs.

Gate Resistance

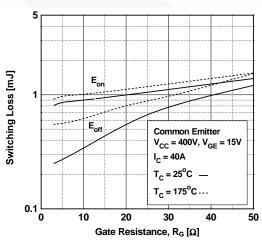
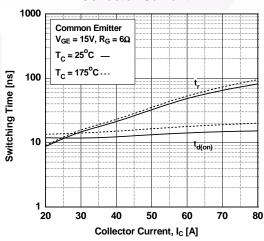


Figure 12. Turn-on Characteristics vs. Collector Current



Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Collector Current

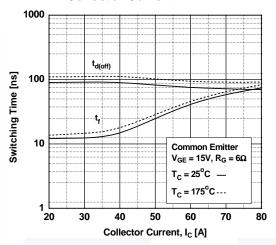


Figure 14. Switching Loss vs. Collector Current

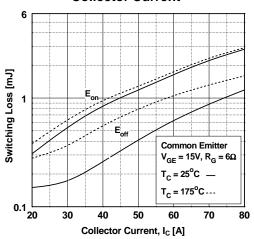


Figure 15. Load Current Vs. Frequency

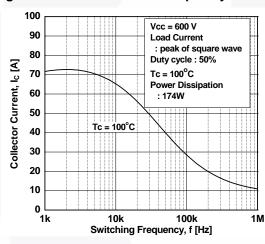


Figure 16. SOA Characteristics

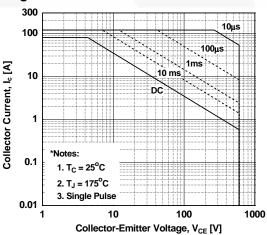
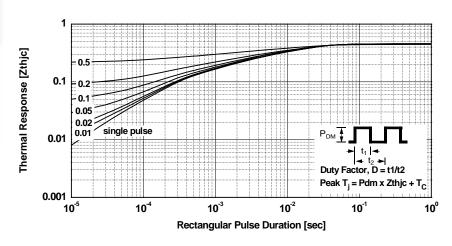


Figure 17. Transient Thermal Impedance of IGBT



Mechanical Dimensions

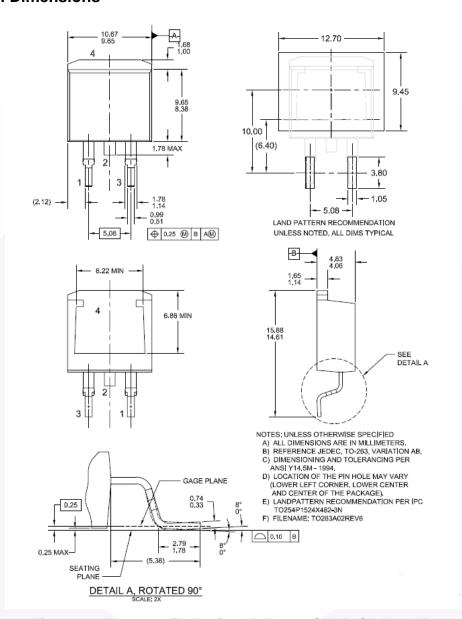


Figure 18. TO-263 2L (D2PAK) - 2LD,TO263, SURFACE MOUNT

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Dimensions in Millimeters





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